

# ES1AD THRU ES1JD

## Surface Mount Superfast Recovery Rectifier

Reverse Voltage – 50 to 600 V

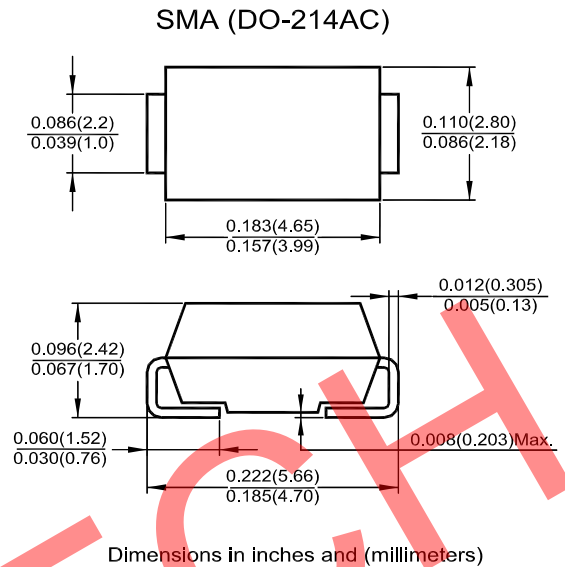
Forward Current – 1 A

### Features

- Plastic package has Underwriters Laboratories Flammability Classification 94V-0
- Easy pick and place
- For surface mounted applications
- Low profile package
- Built-in strain relief
- Superfast recovery times for high efficiency

### Mechanical Data

- **Case:** SMA (DO-214AC), molded plastic
- **Terminals:** Solder plated, solderable per MIL-STD-750, Method 2026 guaranteed
- **Polarity:** Color band denotes cathode end

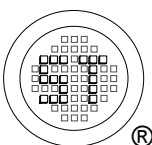


### Absolute Maximum Ratings and Characteristics

Ratings at 25 °C ambient temperature unless otherwise specified. Single phase, half wave, 60 Hz, resistive or inductive load. For capacitive load, derate current by 20 %.

Parameter	Symbols	ES1AD	ES1BD	ES1CD	ES1DD	ES1ED	ES1GD	ES1JD	Units
Maximum Recurrent Peak Reverse Voltage	$V_{RRM}$	50	100	150	200	300	400	600	V
Maximum RMS Voltage	$V_{RMS}$	35	70	105	140	210	280	420	V
Maximum DC Blocking Voltage	$V_{DC}$	50	100	150	200	300	400	600	V
Maximum Average Forward Rectified Current $T_L = 100^\circ\text{C}$	$I_{F(AV)}$	1							A
Peak Forward Surge Current 8.3 ms Single Half Sine Wave Superimposed on Rated Load (JEDEC Method)	$I_{FSM}$	30							A
Maximum Forward Voltage at 1 A	$V_F$	1			1.25		1.7		V
Maximum Reverse Current at $T_a = 25^\circ\text{C}$ at Rated DC Blocking Voltage at $T_a = 100^\circ\text{C}$	$I_R$	5 100							$\mu\text{A}$
Typical Junction Capacitance at $V_R = 4\text{ V}$ , $f = 1\text{ MHz}$	$C_J$	10							pF
Typical Reverse Recovery Time at $I_F = 0.5\text{ A}$ , $I_R = 1\text{ A}$ , $I_{rr} = 0.25\text{ A}$	$t_{rr}$	35						50	ns
Typical Thermal Resistance <sup>1)</sup>	$R_{\theta JL}$	35							$^\circ\text{C/W}$
Operating Junction and Storage Temperature Range	$T_j, T_{stg}$	- 55 to + 150							$^\circ\text{C}$

<sup>1)</sup> Thermal resistance from junction to lead mounted on P.C.B. with 0.3 X 0.3" (8.0 X 8.0 mm ) copper pad areas.



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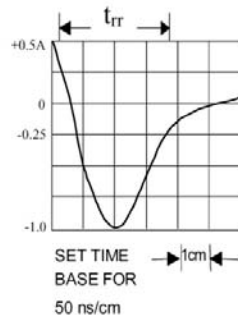
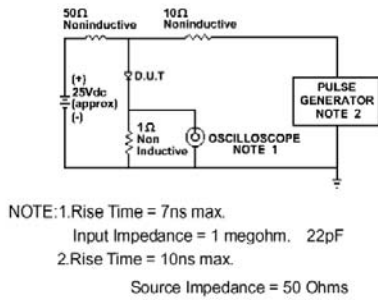


Fig. 1-REVERSE RECOVERY TIME CHARACTERISTIC AND TEST CIRCUIT DIAGRAM

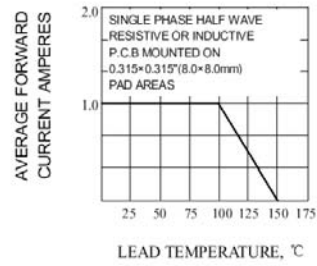


Fig. 2-MAXIMUM AVERAGE FORWARD CURRENT RATING

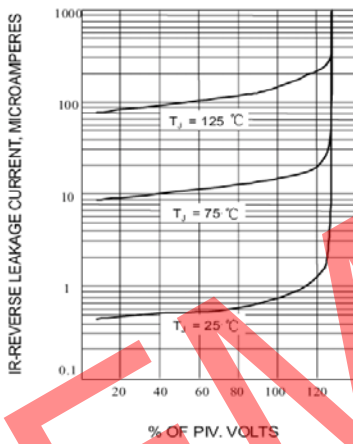


Fig. 3-TYPICAL REVERSE CHARACTERISTICS

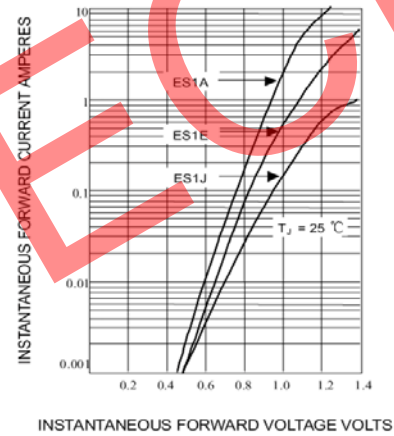


Fig. 4-TYPICAL FORWARD CHARACTERISTICS

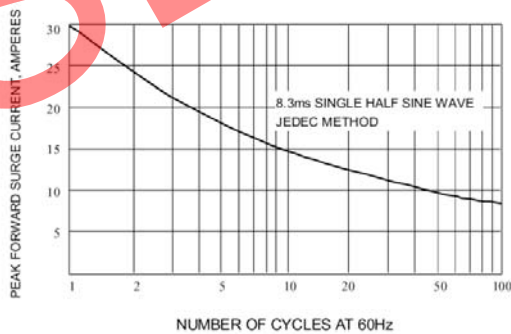


Fig. 5-MAXIMUM NON-REPETITIVE SURGE CURRENT

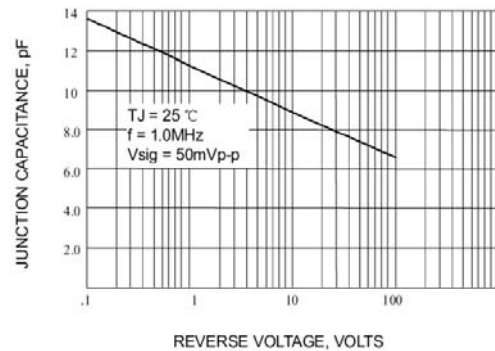
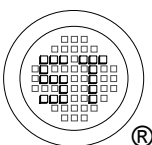


Fig. 6-TYPICAL JUNCTION CAPACITANCE



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